NSN 5961-01-235-3286

Transistor - Page 1 of 2



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Inclosure Material: Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.750 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-39 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case and quality assurance level s **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -80.0 collector to base voltage/static/emitter open and -80.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** -1.00 amperes source cutoff current **Power Rating Per Characteristic:** 0.8 watts small-signal input power, common-collector preset **Transfer Ratio:** 1.5 static forward current transfer ratio, common-emitter and 6.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead

Shelf Life:

Specification Data:

81349-mil-s-19500/512 government specification

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NSN 5961-01-235-3286

Transistor - Page 2 of 2



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Demilitarization:

No

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